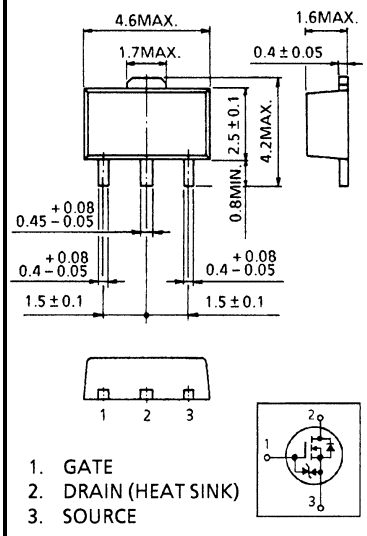
TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSV)

2SK3471

Switching Regulator and DC-DC Converter Applications

- Low drain-source ON-resistance: $R_{DS\ (ON)}$ = 10 Ω (typ.)
- High forward transfer admittance: $|Y_{fs}|$ = 0.4 S (typ.)
- Low leakage current: I_{DSS} = 100 μA (max) (V_{DS} = 500 V)
- Enhancement model: V_{th} = 2.0 to 4.0 V (V_{DS} = 10 V, I_D = 1 mA)

Unit: mm



JEDEC	—
JEITA	SC-62
TOSHIBA	2-5K1B

Weight: 0.05 g (typ.)

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	500	V
Drain-gate voltage (R_{GS} = 20 kΩ)		V_{DGR}	500	V
Gate-source voltage		V_{GSS}	±30	V
Drain current	DC (Note 1)	I_D	0.5	A
	Pulse (Note 1)	I_{DP}	1.5	
Drain power dissipation		P_D	0.5	W
Drain power dissipation	(Note 2)	P_D	1.5	W
Single pulse avalanche energy	(Note 3)	E_{AS}	14.3	mJ
Avalanche current		I_{AR}	0.5	A
Repetitive avalanche energy	(Note 4)	E_{AR}	0.05	mJ
Channel temperature		T_{ch}	150	°C
Storage temperature range		T_{stg}	−55 to150	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient	$R_{th\ (ch\text{-}a)}$	250	°C/W

Note 1: Ensure that the channel temperature does not exceed 150°C

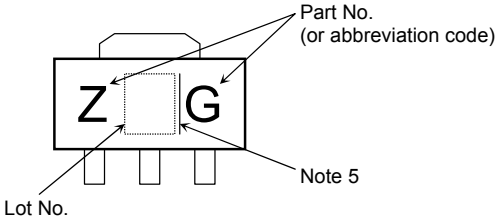
Note 2: Mounted on a ceramic substrate (25.4 mm × 25.4 mm × 0.8 mm)

Note 3: V_{DD} = 90 V, T_{ch} = 25°C (initial), L = 100 mH, R_G = 25 Ω, I_{AR} = 0.5 A

Note 4: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

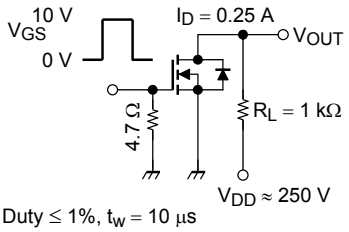
Marking



Note 5: A line beside a Lot No. identifies the indication of product Labels.
Without a line: [[Pb]]/INCLUDES > MCV
With a line: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2002/95/EC of the European Parliament and of the Council of 27 January 2003 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current		I_{GSS}	V_{GS} = ±25 V, V_{DS} = 0 V	—	—	±10	μA
Gate-source breakdown voltage		$V_{(BR)\ GSS}$	I_G = ±10 μA, V_{DS} = 0 V	±30	—	—	V
Drain cut-OFF current		I_{DSS}	V_{DS} = 500 V, V_{GS} = 0 V	—	—	100	μA
Drain-source breakdown voltage		$V_{(BR)\ DSS}$	I_D = 10 mA, V_{GS} = 0 V	500	—	—	V
Gate threshold voltage		V_{th}	V_{DS} = 10 V, I_D = 1 mA	2.0	—	4.0	V
Drain-source ON resistance		$R_{DS\ (ON)}$	V_{GS} = 10 V, I_D = 0.25 A	—	10	18	Ω
Forward transfer admittance		$\|Y_{fs}\|$	V_{DS} = 10 V, I_D = 0.25 A	0.2	0.4	—	S
Input capacitance		C_{iss}	V_{DS} = 10 V, V_{GS} = 0 V, f = 1 MHz	—	75	—	pF
Reverse transfer capacitance		C_{rss}		—	7	—	
Output capacitance		C_{oss}		—	24	—	
Switching time	Rise time	t_r		—	11	—	ns
	Turn-ON time	t_{on}		—	18	—	
	Fall time	t_f		—	54	—	
	Turn-OFF time	t_{off}		—	95	—	
Total gate charge (gate-source plus gate-drain)		Q_g	V_{DD} ≈ 400 V, V_{GS} = 10 V, I_D = 0.5 A	—	3.8	—	nC
Gate-source charge		Q_{gs}		—	1.9	—	
Gate-drain (“miller”) charge		Q_{gd}		—	1.9	—	

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	I_{DR}	—	—	—	0.5	A
Pulse drain reverse current (Note 1)	I_{DRP}	—	—	—	1.5	A
Forward voltage (diode)	V_{DSF}	I_{DR} = 0.5 A, V_{GS} = 0 V	—	—	−1.5	V
Reverse recovery time	t_{rr}	I_{DR} = 0.5 A, V_{GS} = 0 V, dI_{DR}/dt = 100 A / μs	—	190	—	ns
Reverse recovery charge	Q_{rr}		—	380	—	nC

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